

## SSC8039GS1

## **P-Channel Enhancement Mode MOSFET**

#### > Features

VDS	VGS	RDSON Typ.	ID	
201/	1301/	12.5mR@-10V	440	
-30V	±20V	15mR@-4V5	-14A	

## Description

This device is produced with high cell density, DMOS trench technology, which is especially used to minimize on-state resistance. This device is particularly suited for low voltage power management requiring a wild range of given voltage ratings(4.5V-25V) such as load switch and battery protection.

# Applications

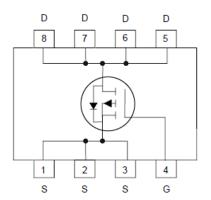
- Load Switch
- NB battery
- DCDC conversion

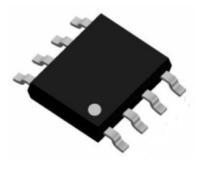
## > Ordering Information

Device	Package	Shipping
SSC8039GS1	SOP8	4000/Reel

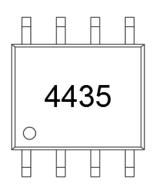
# Pin configuration

Top view





SOP8



Marking



# ➤ Absolute Maximum Ratings(T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Ratings	Unit	
$V_{DSS}$	Drain-to-Source Voltage	-30	V	
V <sub>GSS</sub>	Gate-to-Source Voltage	±20	V	
I <sub>D</sub>	Continuous Drain Current <sup>a</sup>	-14	Α	
I <sub>DM</sub>	Pulsed Drain Current <sup>b</sup>	-50	Α	
P <sub>D</sub>	Power Dissipation <sup>c</sup>	5.5	W	
P <sub>DSM</sub>	Power Dissipation <sup>a</sup>	2.5	W	
Тл	Operation junction temperature -55 to 150		°C	
$T_{STG}$	Storage temperature range	-55 to 150	°C	

# ➤ Thermal Resistance Ratings(T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Typical	Maximum	Unit
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance <sup>a</sup>		55	°C/W
R <sub>0</sub> JC	R <sub>0JC</sub> Junction-to-Case Thermal Resistance		25	C/VV

#### Note:

- a. The value of  $R_{\theta JA}$  is measured with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz.copper,in a still air environment with  $T_A$ =25°C. The value in any given application depends on the user is specific board design. The current rating is based on the t  $\leq$  10s thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.
- c. The power dissipation  $P_D$  is based on  $T_{J(MAX)}$ =150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.

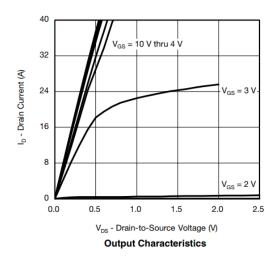


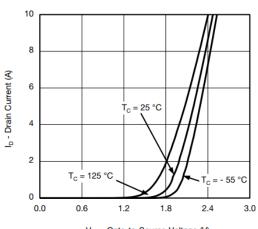
# $\blacktriangleright$ **Electronics Characteristics**(T<sub>A</sub>=25 $^{\circ}$ C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур.	Max	Unit
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	VGS=0V , ID=-250uA	-30			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	VDS=VGS , ID=-250uA	-1	-1.3	-3	٧
	Drain-Source On-	VGS=-10V , ID=-10A		12.5	18	mR
R <sub>DS(on)</sub>	Resistance	VGS=-4.5V , ID=-7A		15	22	
I <sub>DSS</sub>	Zero Gate Voltage  Drain Current	VDS=-30V , VGS=0V			-1	uA
I <sub>GSS</sub>	Gate-Source leak	VGS=±20V , VDS=0V			±100	nA
GFS	Transconductance	VDS=-5V , ID=-10A		18		S
VSD	Forward Voltage	VGS=0V , IS=-1A		-0.7	-1.6	V
Ciss	Input Capacitance	VDS=-20V, VGS=0V, f=1MHz		2000		
Coss	Output Capacitance			550		pF
Crss	Reverse Transfer Capacitance			800		
Qg	Total Gate charge	VGS=-4.5V , VDS=-15V, ID=-7A		14		
Qgs	Gate to Source charge			4.4		nC
Qgd	Gate to Drain charge			2.7		
T <sub>D(ON)</sub>	Turn-on delay time	VGS=-10V, VDS=-15V, RL=1.5R, RG=3R		9		
Tr	Rise time			7		no
T <sub>D(OFF)</sub>	Turn-off delay time			39		ns
Tf	Fall time	110-011		14		

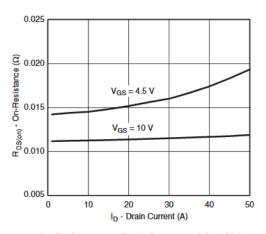


# ➤ Typical Characteristics(T<sub>A</sub>=25°C unless otherwise noted)

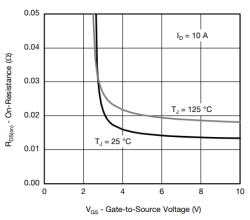




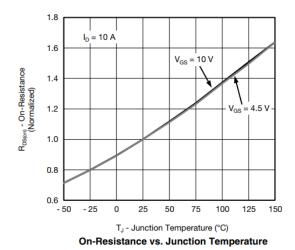
V<sub>GS</sub> - Gate-to-Source Voltage (V) **Transfer Characteristics** 

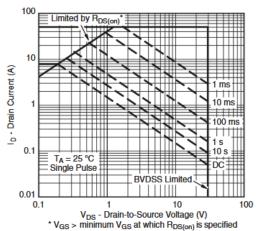






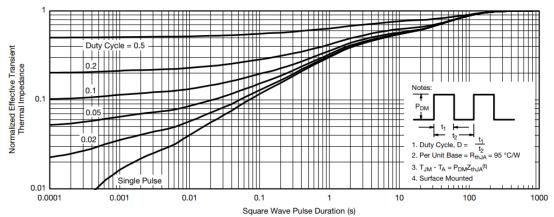
On-Resistance vs. Gate-to-Source Voltage





Safe Operating Area, Junction-to-Ambient

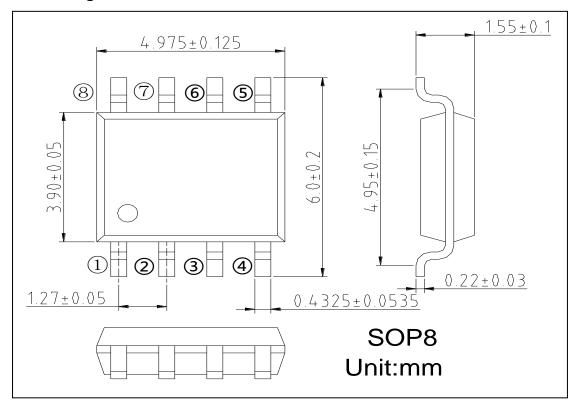




Normalized Thermal Transient Impedance, Junction-to-Ambient



# Package Information



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